## NSN 5961-00-432-0190

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-432-0190 **Inclosure Material:** Glass **Overall Length:** 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.075 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 working peak reverse voltage **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute and 400.00 milliamperes source cutoff current preset and 600.00 milliamperes source cutoff current outside diameter and 4.00 amperes source cutoff current peak **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 18876-mis-19413 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No